

UNISONIC TECHNOLOGIES CO., LTD

USR5VA10

Preliminary

CMOS IC

SYNCHRONOUS RECTIFIER

DESCRIPTION

UTC **USR5VA10** is a synchronous rectifying IC with $20m\Omega/45V$ NMOS and synchronous rectification control IC integrated. It is suitable for flyback switch mode power supply of up to 5V/2A. Efficiency increased by $2\%\sim5\%$ and temperature decreased by up to 50% compared with normal Schottky Barrier Diode, or more than 2% efficiency increase and 20% temperature decrease compared with low VF diode.

FEATURES

- * High efficiency, Low temperature
- * Synchronous rectification, support DCM and QR mode flyback system
- * Internal integrated 20mΩ/45V NMOS
- * Self-power supply design, no need for external power supply
- * Self-detection, no need for external synchronous signal
- * Only 3 poles (V_{CC}-K-A), can directly replace Schottky Barrier Diode

ORDERING INFORMATION



Ordering Number		Dookogo	Pin Assignment							Decking	
Lead Free	Halogen Free	гаскауе	1	2	3	4	5	6	7	8	Facking
USR5VA10L-AA3-R	USR5VA10G-AA3-R	SOT-223	V_{CC}	Κ	А	-	-	I	I	I	Tape Reel
USR5VA10L-TM3-T	USR5VA10G-TM3-T	TO-251	V_{CC}	Κ	А	-	-	I	I	I	Tube
USR5VA10L-S08-R	USR5VA10G-S08-R	SOP-8	Α	А	А	V_{CC}	Κ	K	K	Κ	Tape Reel

USR5VA10G-AA3-R T (1)Packing Type	(1) R: Tape Reel, T: Tube
(2)Package Type	(2) AA3: SOT-223, TM3: TO-251, S08: SOP-8
(3)Green Packag	e (3) G: Halogen Free and Lead Free, L: Lead Free

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MARKING

PACKAGE	MARKING				
SOT-223	USR5VA10 CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICCU CICU				
TO-251	UTC USR5VA10□ L: Lead Free G: Halogen Free Date Code				
SOP-8	8 7 6 5 UTC □□□□ L: Lead Free USR5VA10□ → G: Halogen Free ● □□□ Lot Code 1 2 3				

■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	V _{CC}	Inside power supply, bypass a capacitor between V_{CC} and A
2	К	Same as negative pole of Diode
3	А	Same as positive pole of Diode

BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
P, N Reverse Voltage	V _{PN}	45	V
Operating Temperature	T _A	-25 ~ +120	°C
Storage Temperature	T _{STG}	-55 ~ +155	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC} Operation Voltage	Vcc		7	11	15	V
V _{CC} Start-up Voltage	V _{CC_ON}		4	5	6	V
V _{CC} UVLO	V _{CC_UVLO}		3	4	5	V
Quiescent Current	Icc	V _{CC} =11V	80	150	260	μA
Gate Turn On Threshold	V _{THON}	N point tested first	-230		-50	mV
Gate Turn Off Threshold	VTHOFF		-35	-6	-1	mV
Turn On Delay Time	T _{DON}	From V _{THON} to GATE>2V			200	ns
Turn Off Delay Time	T _{DOFF}	From V _{THOFF} to GATE<9V			50	ns
Internal MOS R _{DSON}	R _{DSON}		15		20	mΩ
Maximum Peak Current	IPEAK	T _A =25°C			60	А
SW to GND Breakdown Voltage	V _{(BR)DSS}		40	45	50	V



DETAILED DESCRIPTION

Self-Power Supply Circuit

There is self-power supply circuit with inside the IC, which can drive the IC and MOS without external power supply.

Start Up

With K pole voltage is higher than A pole, self-power supply circuit will support the power of V_{CC}, V_{CC} voltage increases. If V_{CC} voltage is lower than start up voltage V_{CC_ON}, internal Power MOS is off. When V_{CC} voltage is higher than V_{CC ON}, startup mode is finished. When V_{CC} voltage is lower than V_{CC UVLO}, IC returns to startup mode.

Power MOS Control

If the detected voltage of (K-A) lower than Von, Power MOS will be open. If the detected voltage of (K-A) is higher than V_{THOFF}, Power MOS will be closed.

RC Absorbing Circuit

In status of starting up, output short circuit, over input voltage and CCM modes, there will be peak voltage, as to avoid the breaking of MOS, can add RC absorbing circuit between A and K, so that the peak voltage on N can be reduced.

On-Resistance

During operation, internal resistance increases together with the temperature, efficiency decreases accordingly. It is better to enlarge the heat releasing area so that the IC temperature can be decreased.



TYPICAL APPLICATION CIRCUIT



Figure 1. Forward Rectification Application Circuit



Figure 2. Reverse Rectification Application Circuit

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